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View Online at https://aerobasegroup.com/nsn/5961-01-234-2938

Inclosure Material: Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.090 inches **Function For Which Designed:** Voltage regulator **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and quality assurance level txv **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.3 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 90.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Special Features:** Design analysis **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/127 government specification

Shelf Life:

N/a

- Unit Of Measure:
- ---

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Demilitarization:

No

Fiig:

A110a0

